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Stocking Distributor

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Diodes Incorporated DMN3016LDN-7

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>



Features

Low On-Resistance Low Input Capacitance Fast Switching Speed

Mechanical Data

Case: V-DFN3030-8





DMN3016LDN

30V DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3)

Case Material: Molded Plastic, "Green" Molding Compound.

D1

S1

UL Flammability Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020 Terminal Connections: See Diagram

Product Summary

Device	V _{(BR)DSS}	R _{DS(ON) max}	I _{D MAX} T _A = +25°С
N-Channel	30V	20mΩ @ V _{GS} = 10V	7.3A
N-Channel	301	24mΩ @ V _{GS} = 4.5V	6.7A

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC Motor Control
- DC-AC Inverters

Top View

Notes:

Weight: 0.02 grams (Approximate) G1 D1 8 1 7 S1 2 D1 G1 3 6 S2 D2 D2 G2 5 4

•



Q2 N-Channel MOSFET

D2

S2

Equivalent Circuit

G2

Ordering Information (Note 4)

V-DFN3030-8

Part Number	Case	Packaging
DMN3016LDN-7	V-DFN3030-8	3000/Tape & Reel
DMN3016LDN-13	V-DFN3030-8	10000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

Pin 1

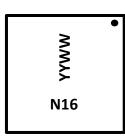
Bottom View

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information



N16 = Product Type Marking Code YYWW = Date Code Marking YY = Last Digit of Year (ex: 13 for 2013) WW = Week Code $(01 \sim 53)$





DMN3016LDN

Characteristic Drain-Source Voltage Gate-Source Voltage			Symbol	Value	Units
			V _{DSS}	30	V
			V _{GSS}	±20	V
	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	7.3 5.8	А
Continuous Drain Current (Note 6) $V_{GS} = 10V$	t<10s	T _A = +25°C T _A = +70°C	I _D	9.2 7.3	А
Maximum Continuous Body Diode Forward Currer		ls	2.5	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	45	А
Avalanche Current (Note 7) L = 0.1mH			I _{AS}	22	А
Avalanche Energy (Note 7) L = 0.1mH			E _{AS}	24	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Units	
Total Power Dissipation (Note 5)	T _A = +25°C	PD	1.1	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Р	119	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	R _{θJA}	75		
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.6	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	78		
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	R _{θJA}	49	°C/W	
Thermal Resistance, Junction to Case (Note 6)		R _{θJC}	13.5		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

0							
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	1	μA	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	1.4	-	2.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Р	-	-	20	mΩ	$V_{GS} = 10V, I_D = 11A$	
	R _{DS(ON)}	-	-	24		$V_{GS} = 4.5V, I_D = 9A$	
Diode Forward Voltage	V _{SD}	•	0.70	1.0	V	$V_{GS} = 0V, I_S = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	•	1415	-		$V_{DS} = 15V, V_{GS} = 0V,$ f = 1.0MHz	
Output Capacitance	C _{oss}	-	119	-	pF		
Reverse Transfer Capacitance	C _{rss}	•	82	-			
Gate Resistance	R _g	-	2.6	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	-	11.3	-			
Total Gate Charge (V _{GS} = 10V)	Qg	-	25.1	-	nC	V _{DS} = 15V, I _D = 12A	
Gate-Source Charge	Q _{gs}	-	3.5	-	no		
Gate-Drain Charge	Q _{gd}	-	3.6	-			
Turn-On Delay Time	t _{D(ON)}	-	4.8	-			
Turn-On Rise Time	t _R	-	16.5	-	ns	$V_{DD} = 15V, V_{GS} = 10V,$ $R_L = 1.25\Omega, R_G = 3\Omega$	
Turn-Off Delay Time	tD(OFF)	-	26.1	-			
Turn-Off Fall Time	tF	-	5.6	-			
Reverse Recovery Time	t _{RR}	-	12.3	-	ns		
Reverse Recovery Charge	Q _{rr}	-	10.4	-	nC	I _F = 12A, di/dt = 500A/μs	

Notes:

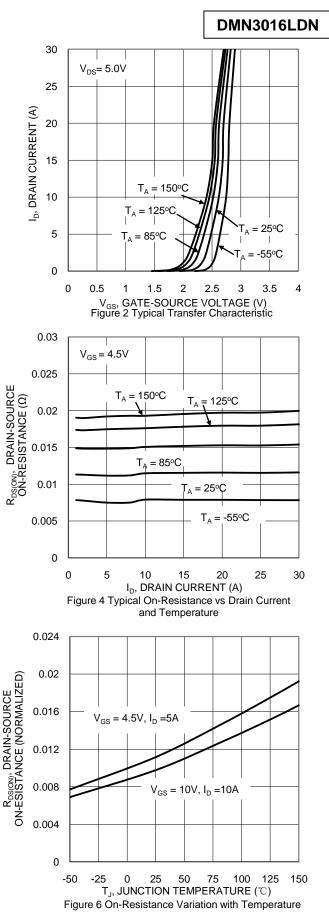
Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1in. square copper plate.

7. I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$. 8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.

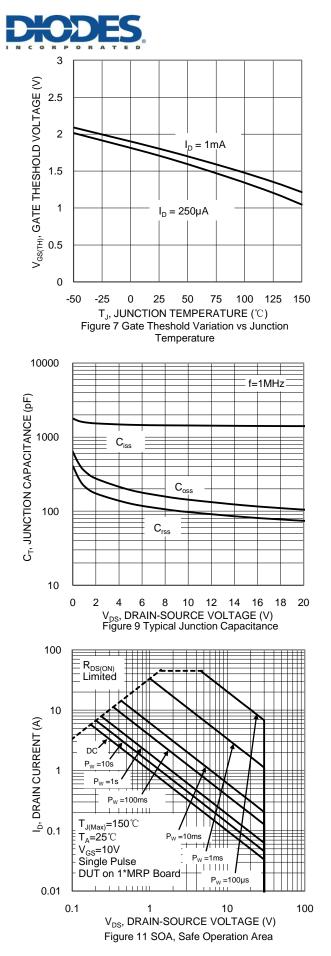


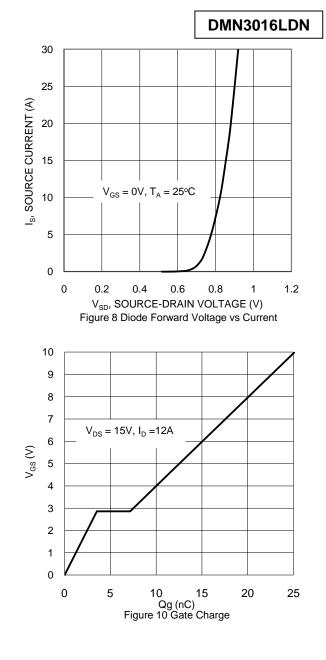
30.0 = 3.5V GS 25.0 = 4.0V $V_{GS} = 3.0V$ I_D, DRAIN CURRENT (A) 20.0 $V_{GS} = 4.5V$ 15.0 V_{GS} = 10.0V 10.0 5.0 V_{GS} = 2.5V $V_{GS} = 2.2V$ 0.0 0 0.5 2 1 1.5 V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure1 Typical Output Characteristic 0.03 R_{DS(ON)}, DRAIN-SOURCE ON-RESISTANCE (Ω) 0.02 V_{GS} = 4.5V 0.01 V_{GS} = 10V 0 10 20 0 5 15 25 30 I_D, DRAIN-SOURCE CURRENT (A) Figure 3 Typical On-Resistance vs Drain Current and Gate Voltage 1.8 R_{DSION}, DRAIN-SOURCE ON-RESISTANCE (NORMALIZED) 8 1 1 1 V_{GS} = 4.5V, I_D =5A $\dot{V}_{GS} = 10V,$ $I_{D} = 10A$ 0.6 -50 -25 0 25 50 75 100 125 150 T_J, JUNCTION TEMPERATURE (°C) Figure 5 On-Resistance Variation with Temperature



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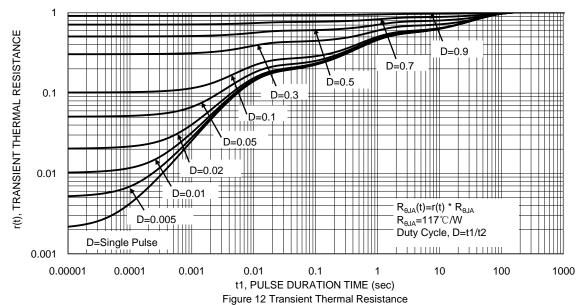


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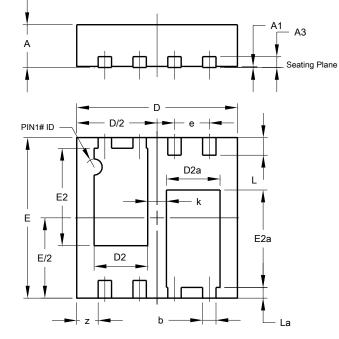




DMN3016LDN

Package Outline Dimensions

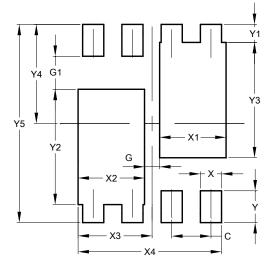
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



V-DFN3030-8 (Type J)					
Dim	Min	Max	Тур		
Α	0.77	0.83	0.80		
A1	0.00	0.05	0.02		
A3	0.203 BSC				
b	0.20	0.30	0.25		
D	2.95	3.050	3.00		
D2	0.90	1.10	1.00		
D2a	0.90	1.10	1.00		
Е	2.95	3.050	3.00		
E2	1.72	1.92	1.82		
E2a	1.72	1.92	1.82		
е	0.65BSC				
L	0.27	0.38	0.33		
La	0.15	0.25	0.20		
k	0.35 TYP				
z	0.40 BSC				
All	All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value		
Dimensions	(in mm)		
С	0.650		
G	0.250		
G1	0.550		
Х	0.350		
X1	1.100		
X2	1.100		
X3	1.225		
X4	2.375		
Y	0.530		
Y1	0.300		
Y2	1.920		
Y3	1.920		
Y4	1.650		
Y5	3.300		





DMN3016LDN

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